L Number	Hits	Search Text	DB	Time stamp
	29	"4885614"	USPAT;	2002/08/13
			US-PGPUB;	15:59
			EPO; JPO;	2000
			DERWENT;	
			IBM TDB	
-	5133	Hunt.in.	USPAT;	2002/08/13
			US-PGPUB;	13:40
			EPO; JPO;	13.10
			DERWENT;	İ
			IBM TDB	
	232	Hunt.in. and charles	USPĀT;	2002/08/13
			US-PGPUB;	13:40
			EPO; JPO;	13.10
			DERWENT;	
			IBM TDB	
-	0	(Hunt.in. and charles) and (silicon near3	USPAT;	2002/08/13
		germanium near3 carbide)	US-PGPUB;	13:40
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	6	(Hunt.in. and charles) and (silicon near3	USPAT;	2002/08/13
		germanium near3 carbon)	US-PGPUB;	13:45
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	672	((silicon adj2 germanium adj2 carbide) or	USPAT;	2002/08/13
		(silicon adj2 germanium adj carbon) or	US-PGPUB;	15:50
		Si-Ge-C or SiGeC)	EPO; JPO;	
			DERWENT;	
1			IBM_TDB	
-	35	(((silicon adj2 germanium adj2 carbide)	USPAT;	2002/08/13
		or (silicon adj2 germanium adj carbon) or	US-PGPUB;	15:52
		Si-Ge-C or SiGeC) same (etch\$3))	EPO; JPO;	
			DERWENT;	
	0100	//	IBM_TDB	0000 (00 (00
-	2100	((silicon near2 germanium near2 carbide)	USPAT;	2002/08/13
	İ	or (silicon near2 germanium near2 carbon)	US-PGPUB;	16:04
	}	or SiGeC or Si-Ge-C)	EPO; JPO;	
			DERWENT;	
_	721	///silicon near? commanium maar? carbida	IBM_TDB USPAT;	2002/08/13
İ	121	<pre>(((silicon near2 germanium near2 carbide) or (silicon near2 germanium near2 carbon)</pre>	US-PGPUB;	16:03
		or SiGeC or Si-Ge-C)) and (etch\$3 or	EPO; JPO;	10.03
		etchant\$1)	DERWENT;	
		00011111071	IBM TDB	
_	15	(((silicon near2 germanium near2 carbide)	USPAT;	2002/08/13
	13	or (silicon near2 germanium near2 carbon)	US-PGPUB;	16:03
		or SiGeC or Si-Ge-C)) and ((etch\$3 or	EPO; JPO;	10.00
		etchant\$1) same (HNA or KOH))	DERWENT;	
	İ		IBM TDB	
_	60	((silicon near2 germanium near2 carbide)	USPAT;	2002/08/13
		or (silicon near2 germanium near2 carbon)	US-PGPUB;	16:05
		or SiGeC or Si-Ge-C) and (HNA or KOH)	EPO; JPO;	
	İ	, ,,	DERWENT;	
			IBM TDB	
- 1	10	(((silicon near2 germanium near2 carbide)	USPAT;	2002/08/13
		or (silicon near2 germanium near2 carbon)	US-PGPUB;	16:06
		or SiGeC or Si-Ge-C) and (HNA or KOH))	EPO; JPO;	
		and (((silicon near2 germanium near2	DERWENT;	
		carbide) or (silicon near2 germanium	IBM TDB	1
İ	ļ	near2 carbon) or SiGeC or Si-Ge-C) same		
	[etch\$3)		
	2999	MEMS	USPAT;	2002/08/13
	İ		US-PGPUB;	16:06
			EPO; JPO;	
			DERWENT;	
1	i i		IBM TDB	1

Search History 8/21/02 2:11:42 PM Page 1

-	5124	cantilever adj (beam or rod)	USPAT;	2002/08/13
			US-PGPUB;	16:07
			EPO; JPO;	10.07
			DERWENT;	
			IBM TDB	
l -	1200	cantilever adj (beam or rod) and	USPAT;	2002 (00 (12
1	1200	(semiconductor or silicon)		2002/08/13
		(Semiconductor of Stricon)	US-PGPUB;	16:08
			EPO; JPO;	
			DERWENT;	
_	4	/MEMC and //gambilassassassis /	IBM_TDB	
	4	(indicate of the following the first tod)	USPAT;	2002/08/13
		and (semiconductor or silicon))) and	US-PGPUB;	16:11
		(SiGe GeSi (Si near2 Ge) or (silicon	EPO; JPO;	
		near1 germanium))	DERWENT;	
			IBM_TDB	
-	98	MEMS and (cantilever adj (beam or rod))	USPAT;	2002/08/13
		and (semiconductor or silicon)	US-PGPUB;	16:12
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	4	1 (1000011) 01 (000,000) 01	USPAT	2002/08/21
		("5344524") or ("5413679")).PN.		10:43
-	21	4885614.urpn.	USPAT;	2002/08/21
	1	_	US-PGPUB;	10:46
			EPO; JPO;	
			DERWENT;	1
			IBM TDB	
_	7	5357899.urpn.	USPAT;	2002/08/21
		•	US-PGPUB;	10:46
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	22	5344524.urpn.	USPAT;	2002/08/21
			US-PGPUB;	10:47
			EPO; JPO;	10.4/
			DERWENT;	
			IBM TDB	
_	4	5413679.urpn.	USPAT;	2002/08/21
	4	OTIO0/9.utpii.	USPAT; US-PGPUB;	10:47
				10:4/
			EPO; JPO;	
			DERWENT;	
	1		IBM TDB	